

# SILICON TRANSISTOR 2SD2425

# NPN SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS AND MID-SPEED SWITCHING

The 2SD2425 is a transistor featuring high current capacitance in small dimension. This transistor is ideal for DC/DC converters and motor drivers.

#### **FEATURES**

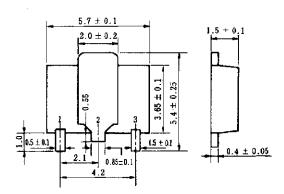
- New package with dimensions in between those of small assessment of small signal and power signal package
- · High current capacitance
- · Low collector saturation voltage
- · Complementary transistor with 2SB1578

#### **QUALITY GRADES**

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### PACKAGE DRAWING (UNIT: mm)



Electrode connection

- 1. Emitter
- 2. Collector
- 3.Base

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>		60	V
Collector to emitter voltage	VCEO		60	V
Emitter to base voltage	V <sub>EBO</sub>		6.0	V
Collector current (DC)	Ic(DC)		5.0	Α
Collector current (pulse)	IC(pulse)	PW ≤ 10 ms, duty cycle ≤ 50 %	7.0	Α
Base current (DC)	I <sub>B(DC)</sub>		1.0	Α
Total power dissipation	Рт	$7.5~\text{cm}^2 \times 0.7~\text{mm}$ ceramic board mounted	2.0	W
Junction temperature	Tj		150	°C
Storage temperature	Tstg		-55 to +150	°C

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



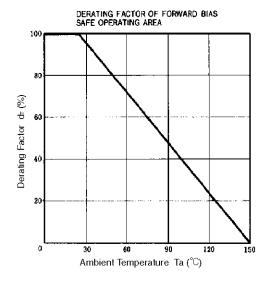
#### **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

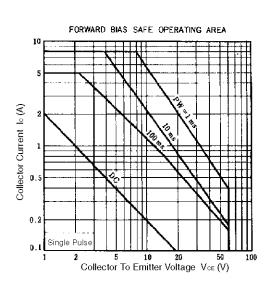
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	VcB = 50 V, IE = 0			10	μΑ
Emitter cutoff current	Ієво	V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0			10	μΑ
DC current gain	h <sub>FE1</sub>	VcE = 1.0 V, Ic = 0.1 A	60	180		_
DC current gain	h <sub>FE2</sub>	VcE = 1.0 V, Ic = 2.0 A	100	200	400	_
DC current gain	h <sub>FE3</sub>	Vce = 2.0 V, Ic = 5.0 A	50	150		_
Collector saturation voltage	V <sub>CE(sat)</sub>	Ic = 2.0 A, I <sub>B</sub> = 0.2 A		90	300	mV
Base saturation voltage	V <sub>BE(sat)</sub>	Ic = 2.0 A, I <sub>B</sub> = 0.2 A		0.9	1.2	V
Turn-on time	ton	Ic = 2.0 A, Vcc= 10 V		0.6		μs
Storage time	tstg	$I_{B1} = -I_{B2} = 0.2 \text{ A}$ $R_L = 5.0 \Omega$		0.8		μs
Fall time	tf			0.08		μs

## hee CLASSIFICATION

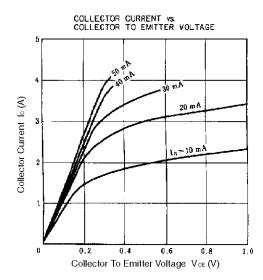
Marking	AB1	AB2	AB3	
h <sub>FE2</sub>	100 to 200	160 to 320	200 to 400	

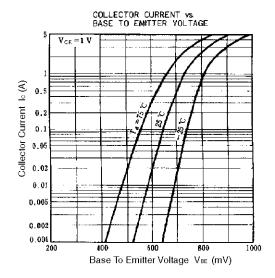
### TYPICAL CHARACTERISTICS (Ta = 25°C)



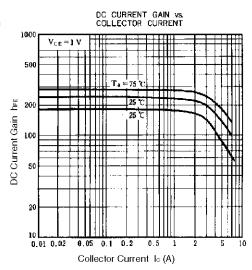


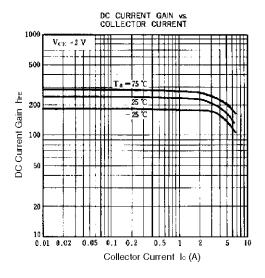


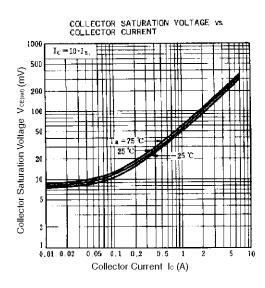


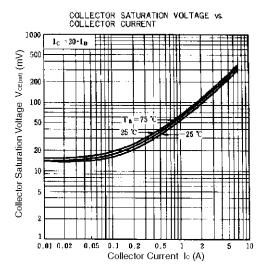


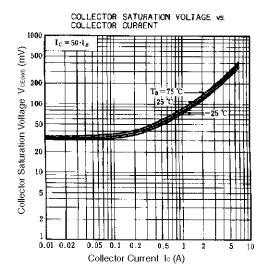
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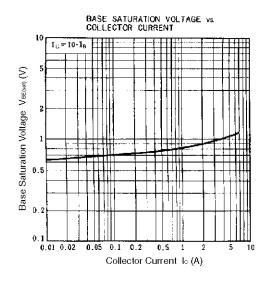


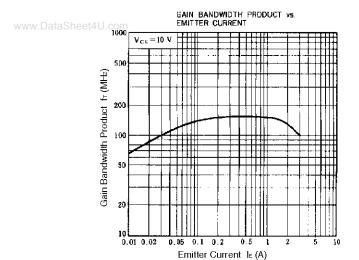


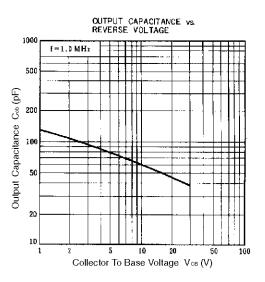


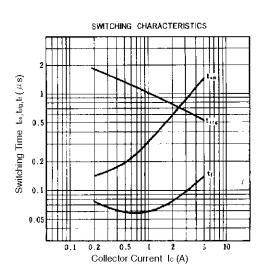












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